

September 2007

# TN2907A PNP General Purpose Amplifier

- · This device is designed for use as a general purpose amplifier and switch requiring collector currents to 500 mA.
- · Sourced from process 63.



TO-226

1. Collector 2. Base 3. Emitter

# Absolute Maximum Ratings\* T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V <sub>CBO</sub>	Collector-Base Voltage	60	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	60	V	
V <sub>EBO</sub>	Emitter-Base Voltage	5	V	
I <sub>C</sub>	Collector Current - Continuous 800		mA	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 ~ 150	°C	

<sup>\*</sup> This ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### NOTES

- 1) These rating are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.
- 3) All voltages (V) and currents (A) are negative polarity for PNP transistors.

# Thermal Characteristics $T_a=25$ °C unless otherwise noted

Symbol	Parameter	Max.	Units
P <sub>D</sub>	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

1

Units

# $\textbf{Electrical Characteristics*} \ \, \mathbf{T_{a}\text{=}25 \times C} \ \, \mathbf{unless \ otherwise \ noted}$

Parameter

Off Characteristics					
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_{C} = 10\mu A, I_{E} = 0$	60		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_{C} = 10\mu A, I_{E} = 0$	60		V
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C = 10 \text{mA}, I_E = 0$	5		V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 50 \text{ V}, I_{E} = 0$		10	nA
		$V_{CB} = 50 \text{ V}, I_E = 0, T_A = 150C$		10	μΑ
I <sub>CEX</sub>	Collector Cut-off Current	$V_{CE} = 30 \text{ V}, V_{BE} = 0.5 \text{ V}$		50	nA

**Test Condition** 

Min.

Max.

# On Characteristics

Symbol

h <sub>FE</sub>	DC Current Gain	Ic = 0.1 mA, VcE = 10 V	75		
		Ic = 1.0 mA, VcE = 10 V	100		
		Ic = 10  mA, Vce = 10  V	100		
		$Ic = 150 \text{ mA}, VcE = 10 \text{ V}^*$	100	300	
		$I_C = 500 \text{ mA}, V_{CE} = 10 \text{ V}^*$	50		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	Ic = 150 mA, Iв = 15 mA*		0.4	V
		$I_C = 500 \text{ mA}, I_B = 50 \text{ mA}^*$		1.6	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	Ic = 150 mA, Iв = 15 mA*		1.3	V
		$I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$		2.6	V

# **Small Signal Characteristics**

Cobo	Output Capacitance	VcB = 10 V, IE = 0, f = 100 kHz	8.0	pF
Cibo	Input Capacitance	V <sub>EB</sub> = 2.0 V, I <sub>C</sub> = 0, f = 100 kHz	30	pF

<sup>\*</sup> Pulse Test: Pulse Width £ 300ms, Duty Cycle = 2%

NOTES:
1) All voltages (V) and currents (A) are negative polarity for PNP transistors.





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